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***Quantum Dots, Nanostructures, and
Quantum Materials: Growth,
Characterization, and Modeling XVII***

**Diana L. Huffaker
Holger Eisele**
Editors

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Contents

v	<i>Authors</i>
vii	<i>Conference Committee</i>

QUANTUM DOTS

11291 04	Investigations on heterogeneously coupled Submonolayer (SML) on Stranski-Krastanov (SK) quantum dot heterostructures with higher (0.1ML/sec) and lower (0.05ML/sec) growth rates [11291-3]
11291 05	Impact of growth rate variabilities of quantum dots and capping layer on photoluminescence of epitaxially grown InAs quantum dots [11291-4]
11291 07	Directed self-assembly of InAs quantum dots using in-situ interference lithography [11291-6]

DEVICES

11291 09	Metal oxide control of exciton-plasmon coupling [11291-8]
----------	--

OPTICAL PROPERTIES AND NOVEL MATERIALS

11291 0H	Resonant energy transfer properties of perovskite nanocrystals [11291-14]
----------	--

NOVEL NANO STRUCTURES

11291 0J	GaAsP nanowires containing intentional and self-forming quantum dots (Invited Paper) [11291-16]
11291 0K	A needle in a needlestack: exploiting functional inhomogeneity for optimized nanowire lasing (Invited Paper) [11291-37]
11291 0N	Novel synthesis of graphene quantum dots using L-aspartic acid [11291-19]

POSTER SESSION

11291 0O	Enhanced optical performance through growth strategy in coupled InAs P-i-P QDIPs [11291-20]
----------	--

- 11291 0P **Optimization of strain-coupled InAs QD layers in P-i-P infrared photodetector heterostructures** [11291-21]
- 11291 0Q **Submonolayer quantum dots in P-i-P configuration: study on effects of monolayer coverage and stacking variations** [11291-22]
- 11291 0R **Selective hydrothermal growth of MnO₂ nanostructures using laser under ambient conditions** [11291-23]
- 11291 0S **Optoelectronic properties of arginine-doped tungsten disulfide quantum dots synthesized via microwave heating** [11291-24]
- 11291 0V **Spatially resolved thermoelectric response of mixed states** [11291-27]
- 11291 0Y **A comparative analysis between heterogeneously coupled Stranski-Krastanov (SK) on Submonolayer (SML) and Submonolayer (SML) on Stranski-Krastanov (SK) quantum dot heterostructures** [11291-30]
- 11291 0Z **Optical and structural behaviour of InAs quantum dots grown on the Si substrate without Si-Ge graded layer and without migration enhanced epitaxy layer** [11291-31]
- 11291 11 **Optical metrology for nanowires grown with molecular beam epitaxy** [11291-34]
- 11291 13 **Optical properties of hybrid films of inhomogeneous ensemble of gold nanoparticles coated by cyanine J-aggregates** [11291-38]

Authors

Numbers in the index correspond to the last two digits of the seven-digit citation identifier (CID) article numbering system used in Proceedings of SPIE. The first five digits reflect the volume number. Base 36 numbering is employed for the last two digits and indicates the order of articles within the volume. Numbers start with 00, 01, 02, 03, 04, 05, 06, 07, 08, 09, 0A, 0B...0Z, followed by 10-1Z, 20-2Z, etc.

Alanis, Juan A., 0K
Bailey, Christopher G., 0H
Beanland, Richard, 0J
Behera, Saraswati, 07
Binder, Johannes, 0V
Caigas, Septem P., 0S
Chakrabarti, Subhananda, 04, 05, 0O, 0P, 0Q, 0Y, 0Z
Charlton, Martin D. B., 0H
Dabrowski, Paweł, 0V
Dadadzhanov, Daler R., 13
Das, Debabrata, 04, 0O, 0P, 0Q, 0Y
Davis, George D., 0J
Dongre, Suryansh, 04, 05, 0O, 0P, 0Q, 0Z
Fonseka, H. Aruni, 0J
Gazi, Sanowar Alam, 05, 0O, 0P, 0Q, 0Z
Gladskikh, Igor A., 13
Godde, Tillmann, 0J
Gott, James A., 0J
Han, Im Sik, 07
Hansen, Poul Erik, 11
Hopkinson, Mark, 07
Hwang, Suwon, 0R
Hwang, Tae Seung, 0R
Jagadish, Chennupati, 0K
Jensen, Søren Alkærsig, 11
Jin, Chao Yuan, 07
Kanaras, Antonios G., 0H
Kanne, Thomas, 11
Klusek, Zbigniew, 0V
Kong, Heejung, 0R
Kumar, Abhishek, 0O, 0P, 0Q
Kumar, Ravinder, 0O, 0P, 0Q, 0Z
Łacińska, Ewa, 0V
Lagoudakis, Pavlos G., 0H
Lin, Tzu-Neng, 0S
Liu, Huiyun, 0J, 0K
Ludwiczak, Katarzyna, 0V
Lutsyk, Iaroslav, 0V
Lysevych, Mykhaylo, 0K
Mercier, Thomas M., 0H
Møller Madsen, Jonas Skovlund, 11
Mowbray, David J., 0J
Nabiullina, Rezida D., 13
Nygård, Jesper, 11
Panda, Debiprasad, 04, 05, 0O, 0P, 0Q, 0Y, 0Z
Pandey, Nivedita, 0O, 0P, 0Q
Parkinson, Patrick, 0K
Piana, Giacomo, 0H
Prasad, Suparnamaaya, 0N
Ranjan Mantri, Manas, 05
Rogala, Maciej, 0V
Sadeghi, Seyed M., 09
Saha, Jhuma, 04, 0Y, 0Z
Samesta, 04, 0Y
Sanchez, Ana M., 0J
Santiago, Svette Reina Merden S., 0S
Shaw, Peter J., 0H
Shen, Ji-Lin, 0S
Skalsky, Stefan, 0K
Starovoytov, Anton A., 13
Stepniewski, Roman, 0V
Tan, Hark Hoe, 0K
Velichko, Anton V., 0J
Wang, Yun Ran, 07
Weng, Chih-Ying, 0S
Wing, Waylin J., 09
Wysmołek, Andrzej, 0V
Yeo, Junyeob, 0R
Zhang, Yunyan, 0J, 0K

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